NSN 5962-01-124-9566

Memory Microcircuit - Page 1 of 1



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| Body Length: | |
|---------------------------|--|
| 0.840 inches | |
| Body Width: | |
| 0.310 inches | |
| Body Height: | |
| 0.185 inches | |
| Maximum Power Dissi | pation Rating: |
| 794.0 milliwatts | |
| Operating Tempuratur | e Range: |
| -55.0/+125.0 degrees ce | elsius |
| Storage Tempurature | Range: |
| -65.0/+150.0 degrees ce | elsius |
| Features Provided: | |
| Monolithic and bipolar a | nd schottky and programmed and high speed and high reliability |
| Inclosure Material: | |
| Ceramic | |
| Inclosure Configuratio | on: |
| Dual-in-line | |
| Output Logic Form: | |
| Transistor-transistor log | ic |
| Input Circuit Pattern: | |
| 10 input | |
| Terminal Surface Trea | tment: |
| Solder | |
| Voltage Rating And Ty | pe Per Characteristic: |
| -0.5 volts power source | and 7.0 volts power source |
| Time Rating Per Chact | teristic: |
| 85.00 nanoseconds pro | pagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low leve |
| output | |
| Memory Device Type: | |
| Prom | |
| Terminal Type And Qu | antity: |
| 16 printed circuit | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| Yes - demil/mli | |
| Fiig: | |
| A458a0 | |